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Substitute for Form 1449/A/P

Complete if Known **Application Number** 10/540,729 Filing Date June 24, 2005 **First Named Inventor** Stephane Taunier 1795 Group Art Unit Phasge **Examiner Name**

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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		U.S. Patent Document			Date of Publication of	Pages, Columns, Lines, Where
Examiner Initials	Cite No.	Number	Kind Code ² (if known)	Name of Patentee or Applicant of Cited Document	Cited Document MM-DD-YYYY	Relevant Passages or Relevant Figures Appear
/A.P./	i	5,275,714		Bonnet et al.	01/04/1994	
/A.P./	2	2002/0189665	A1	Bhattacharya	12/19/2002	
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Examiner Initials	Cite	Office	Foreign Patent Doci	Kind Code ⁵	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	7°
/A.P./	No.1	+	WO 02/077322	(if known)	Bhattacharya, Raghu, Nath	-03/22/2001	IO/AUA	
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		OTHER INFORMATION - NON PATENT LITERATURE DOCUMENTS	
Examiner Initiats	Cite No.1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T²
	4		T
/A.P./		International Search Report	
	5		
/A.P./		PAULA OBREJA ET AL.; "Preparation and Properties of Electrodeposited InSe and Cu.Se Thin Films"; Semiconductor Conference; 1998; pp. 233-236.	
/A.P./	6	FALL ET AL.; "Electrochemical and Spectroscopic Properties of Poly(3-methoxythiophene) Electrosynthesized in an Aqueous Micellar Medium"; Abstract, Database Inspec 'Online!, The Institution of Electrical Engineers, Stevenage GB; XP002254320; Synthetic Metals, Elsevier, Switzerland, Vol. 93, No. 3, 31 March 1998; pp. 175-179; ISSN: 0379-6779.	

¹Unique citation designation number. ²See attached Kinds of U.S. Patent Documents. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent document, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. Skind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. Applicant is to place a check mark here if English language translation is attached.